

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Pulse Power Dissipation (Non Repetitive Current Pulse Derated Above T _A = +25°C) (Note 5)	P _{PK}	400	W
Peak Forward Surge Current, 8.3ms Single Half Sine Wave Superimposed on Rated Load (Notes 5 & 6)	I _{FSM}	40	A
Steady State Power Dissipation @ T _L = +75°C	PM(AV)	1.0	W
Instantaneous Forward Voltage @ I _{PP} = 35A (Notes 5 & 6)	V _F	3.5	V

Notes: 5. Valid provided that terminals are kept at ambient temperature.
6. Measured with 8.3ms single half sine-wave. Duty cycle = 4 pulses per minute maximum.

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Terminal (Note 7)	R _{θJT}	37	°C/W
Typical Thermal Resistance, Junction to Terminal (Note 8)	R _{θJT}	39	°C/W
Typical Thermal Resistance, Junction to Ambient (Note 7)	R _{θJA}	114	°C/W
Typical Thermal Resistance, Junction to Ambient (Note 8)	R _{θJA}	88	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 7. Device mounted on FR-4 substrate, 1"×1", 2oz, single-sided, PC boards with 0.06"×0.09" copper pad.
8. Device mounted on FR-4 substrate, 0.4"×0.5", 2oz, single-sided, PC boards with 0.2"×0.25" copper pad.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

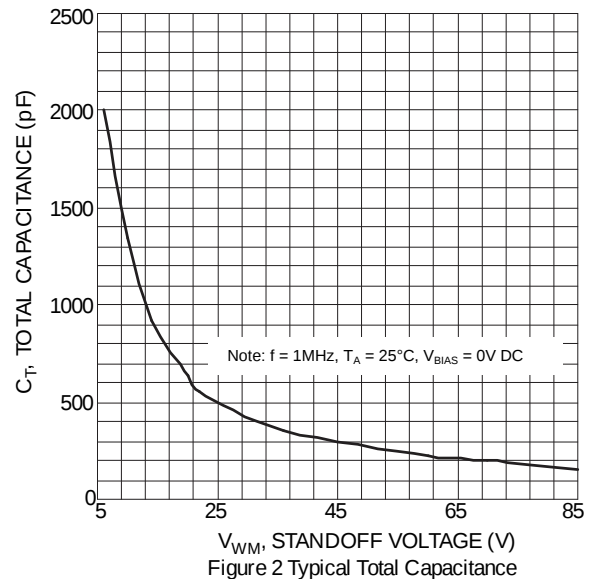
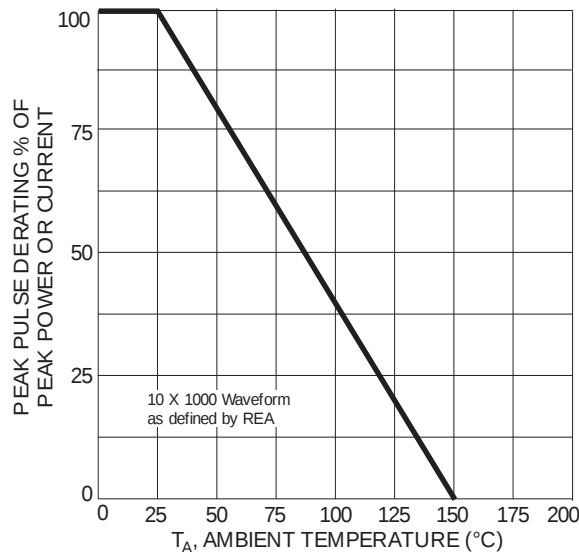
Part Number	Reverse Standoff Voltage	Breakdown Voltage		Test Current	Max. Reverse Leakage @	Max. Clamping Voltage @ I _{PP}	Max. Peak Pulse Current	Marking Code
	V _{RWM} (V)	V _{BR} @ I _T (Note 9)	V _{BR} @ I _T (Note 9)	I _T (mA)	V _{RWM}	V _C (V)	I _{PP} (A)	
P4SMAJ5.0ADF	5.0	6.40	7.25	10	400	9.2	43.5	HE
P4SMAJ6.0ADF	6.0	6.67	7.37	10	400	10.3	38.8	HG
P4SMAJ6.5ADF	6.5	7.22	7.98	10	250	11.2	35.7	HK
P4SMAJ7.0ADF	7.0	7.78	8.60	10	100	12.0	33.3	HM
P4SMAJ7.5ADF	7.5	8.33	9.21	1.0	50	12.9	31.0	HP
P4SMAJ8.0ADF	8.0	8.89	9.83	1.0	25	13.6	29.4	HR
P4SMAJ8.5ADF	8.5	9.44	10.82	1.0	10	14.4	27.7	HT
P4SMAJ9.0ADF	9.0	10.0	11.5	1.0	5.0	15.4	26.0	HV
P4SMAJ10ADF	10	11.1	12.3	1.0	1.0	17.0	23.5	HX
P4SMAJ11ADF	11	12.2	13.5	1.0	1.0	18.2	22.0	HZ
P4SMAJ12ADF	12	13.3	14.7	1.0	1.0	19.9	20.1	IE
P4SMAJ13ADF	13	14.4	15.9	1.0	1.0	21.5	18.6	IG
P4SMAJ14ADF	14	15.6	17.2	1.0	1.0	23.2	17.2	IK
P4SMAJ15ADF	15	16.7	18.5	1.0	1.0	24.4	16.4	IM
P4SMAJ16ADF	16	17.8	19.7	1.0	1.0	26.0	15.3	IP
P4SMAJ17ADF	17	18.9	20.9	1.0	1.0	27.6	14.5	IR
P4SMAJ18ADF	18	20.0	22.1	1.0	1.0	29.2	13.7	IT
P4SMAJ20ADF	20	22.2	24.5	1.0	1.0	32.4	12.3	IV
P4SMAJ22ADF	22	24.4	26.9	1.0	1.0	35.5	11.2	IX
P4SMAJ24ADF	24	26.7	29.5	1.0	1.0	38.9	10.3	IZ
P4SMAJ26ADF	26	28.9	31.9	1.0	1.0	42.1	9.5	JE
P4SMAJ28ADF	28	31.1	34.4	1.0	1.0	45.4	8.8	JG
P4SMAJ30ADF	30	33.3	36.8	1.0	1.0	48.4	8.3	JK
P4SMAJ33ADF	33	36.7	40.6	1.0	1.0	53.3	7.5	JM
P4SMAJ36ADF	36	40.0	44.2	1.0	1.0	58.1	6.9	JP

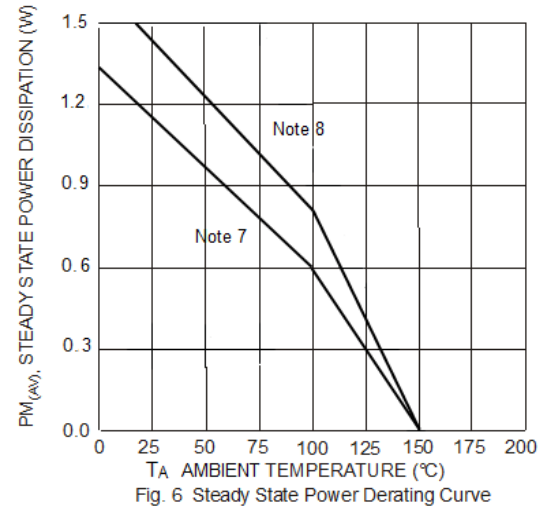
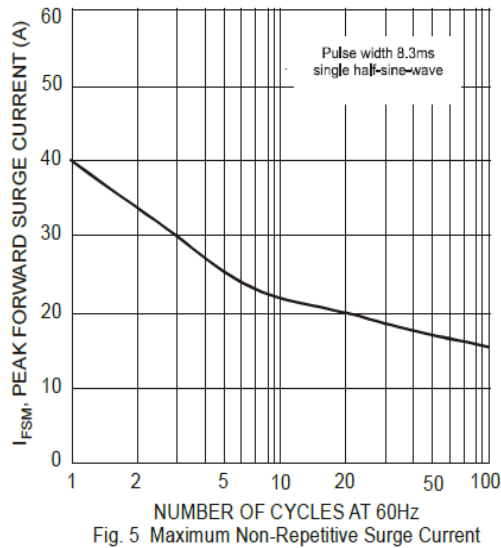
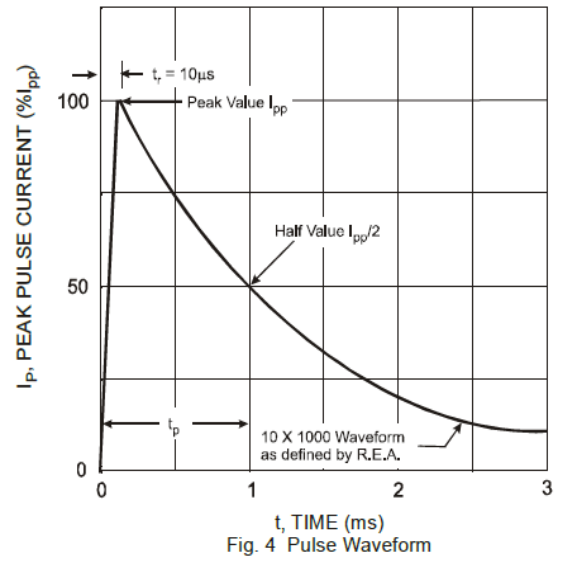
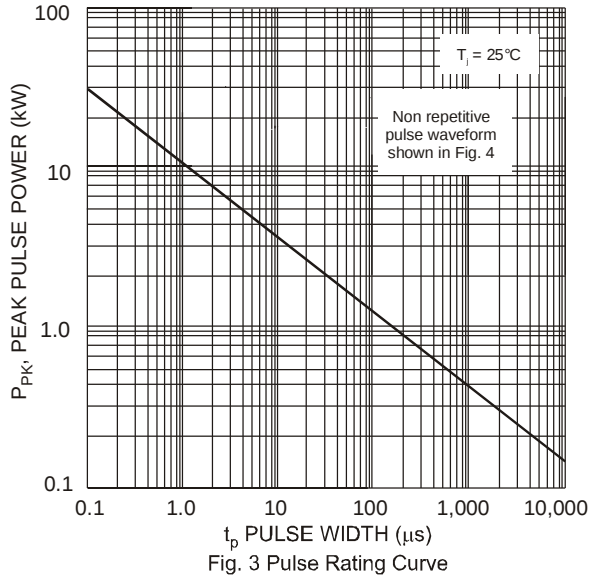
Notes: 9. V_{BR} measured with I_T current pulse = 10ms to 15ms.
10. Per 10 × 1000μs waveform. See Figure 4.

Electrical Characteristics (continued) (@T_A = +25°C, unless otherwise specified.)

Part Number	Reverse Standoff Voltage	Breakdown Voltage		Test Current	Max. Reverse Leakage @	Max. Clamping Voltage @ I _{PP}	Max. Peak Pulse Current	Marking Code
	V _{RWM} (V)	V _{BR} @ I _T (Note 9)		I _T (mA)	V _{RWM} I _R (μA)	V _C (V)	I _{PP} (A)	
P4SMAJ40ADF	40	44.4	49.1	1.0	1.0	64.5	6.2	JR
P4SMAJ43ADF	43	47.8	52.8	1.0	1.0	69.4	5.7	JT
P4SMAJ45ADF	45	50.0	55.3	1.0	1.0	72.7	5.5	JV
P4SMAJ48ADF	48	53.3	58.9	1.0	1.0	77.4	5.2	JX
P4SMAJ51ADF	51	56.7	62.7	1.0	1.0	82.4	4.9	JZ
P4SMAJ54ADF	54	60.0	66.3	1.0	1.0	87.1	4.6	RE
P4SMAJ58ADF	58	64.4	71.2	1.0	1.0	93.6	4.3	RG
P4SMAJ60ADF	60	66.7	73.7	1.0	1.0	96.8	4.1	RK
P4SMAJ64ADF	64	71.1	78.6	1.0	1.0	103	3.9	RM
P4SMAJ70ADF	70	77.8	86.0	1.0	1.0	113	3.5	RP
P4SMAJ75ADF	75	83.3	92.1	1.0	1.0	121	3.3	RR
P4SMAJ78ADF	78	86.7	95.8	1.0	1.0	126	3.2	RT
P4SMAJ85ADF	85	94.4	104	1.0	1.0	137	2.9	RV

Notes: 9. V_{BR} measured with I_T current pulse = 10ms to 15ms.
 10. Per 10 × 1000μs waveform. See Figure 4.

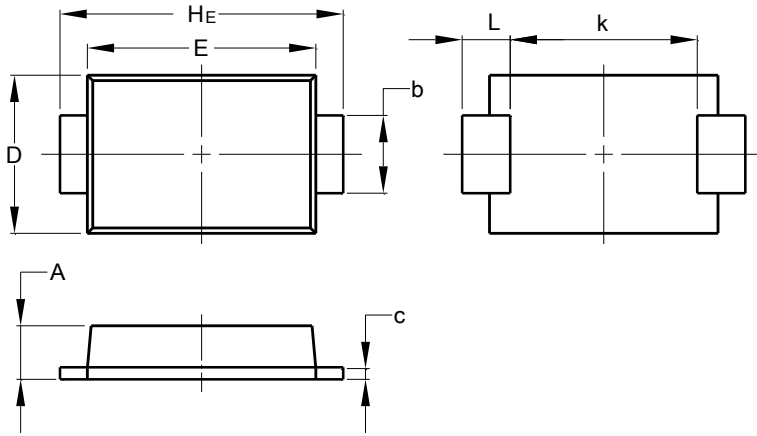




Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

D-FLAT

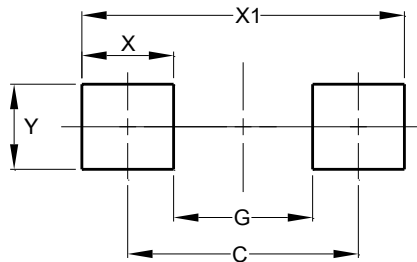


D-FLAT		
Dim	Min	Max
A	0.90	1.10
b	1.25	1.65
c	0.10	0.40
D	2.25	2.95
E	3.95	4.60
k	2.80	-
HE	5.00	5.60
L	0.50	1.30
All Dimensions in mm		

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

D-FLAT



Dimensions	Value (in mm)
C	4.65
G	2.80
X	1.85
X1	6.50
Y	1.70

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